NSN 5961-01-049-0895

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View Online at https://aerobasegroup.com/nsn/5961-01-049-0895 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 drain to gate voltage and 40.0 drain to source voltage and -40.0 reverse gate to source voltage **Current Rating Per Characteristic:** 50.00 milliamperes forward gate current **Power Rating Per Characteristic:** 300.0 milliwatts total power dissipation **Test Data Document:** 50027-9999-5005 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Demilitarization:No **Fiig:**

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